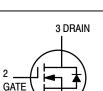
FET Transistor N–Channel — Enhancement

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Drain-Source Voltage	V _{DSS}	60	Vdc
Drain–Gate Voltage (R_{GS} = 1 M Ω)	V _{DGR}	60	Vdc
Gate–Source Voltage – Continuous – Non–repetitive (t _p ≤ 50 μs)	V _{GS} V _{GSM}	± 20 ± 40	Vdc Vpk
Drain Current Continuous Pulsed	I _D I _{DM}	190 1000	mAdc
Total Power Dissipation @ T _A = 25°C Derate above 25°C	PD	400 3.2	mW mW/°C
Operating and Storage Temperature Range	T _J , T _{stg}	-55 to +150	°C





1 SOURCE

THERMAL CHARACTERISTICS

Characteristics	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient	R_{\thetaJA}	312.5	°C/W
Maximum Lead Temperature for Soldering Purposes, 1/16" from case for 10 seconds	ΤL	300	°C

ELECTRICAL CHARACTERISTICS ($T_C = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit	
OFF CHARACTERISTICS					
Drain–Source Breakdown Voltage ($V_{GS} = 0, I_D = 100 \ \mu A$)	V _{(BR)DSS}	60	_	Vdc	
Zero Gate Voltage Drain Current $(V_{DS} = 48 \text{ Vdc}, V_{GS} = 0)$ $(V_{DS} = 48 \text{ Vdc}, V_{GS} = 0, T_J = 125^{\circ}\text{C})$	I _{DSS}		10 500	μAdc	
Gate–Body Leakage Current, Forward (V _{GSF} = 30 V, V _{DS} = 0)	I _{GSSF}	—	-100	nAdc	
ON CHARACTERISTICS ⁽¹⁾	·				

Gate Threshold Voltage ($V_{DS} = V_{GS}$, $I_D = 1.0$ mA)		0.8	2.5	Vdc
Static Drain–Source On–Resistance ($V_{GS} = 10 \text{ V}, \text{ I}_D = 500 \text{ mA}$) ($V_{GS} = 10 \text{ V}, \text{ I}_D = 500 \text{ mA}, \text{ T}_C = 125^{\circ}\text{C}$)	r _{DS(on)}		5.0 9.0	Ω
Drain–Source On–Voltage ($V_{GS} = 5.0 \text{ V}, I_D = 200 \text{ mA}$) ($V_{GS} = 10 \text{ V}, I_D = 500 \text{ mA}$)	V _{DS(on)}		1.5 2.5	Vdc
On–State Drain Current (V _{GS} = 10 V, V _{DS} \ge 2.0 V _{DS(on)})	I _{D(on)}	750	—	mAdc
Forward Transconductance (V _{DS} \ge 2.0 V _{DS(on)} , I _D = 500 mA)		100	—	μmhos

1. Pulse Test: Pulse Width $\leq\,$ 300 $\mu s,$ Duty Cycle $\leq\,$ 2.0%.

VN0610LL

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ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted) (Continued)

Characteristic		Symbol	Min	Max	Unit
DYNAMIC CHARACTERISTIC	CS				
Input Capacitance		C _{iss}	—	60	pF
Output Capacitance	(V _{DS} = 25 Vdc, V _{GS} = 0, f = 1.0 MHz)	C _{oss}	—	25	
Reverse Transfer Capacitance		C _{rss}	—	5.0	
SWITCHING CHARACTERIS	TICS ⁽¹⁾				
Turn–On Delay Time	(V _{DD} = 15 Vdc, I _D = 600 mA,	t _{on}	—	10	ns
Turn–Off Delay Time	$R_{gen} = 25 \ \Omega, \ R_L = 23 \ \Omega)$	t _{off}	—	10	1

1. Pulse Test: Pulse Width \leq 300 ms, Duty Cycle \leq 10%.

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RESISTIVE SWITCHING

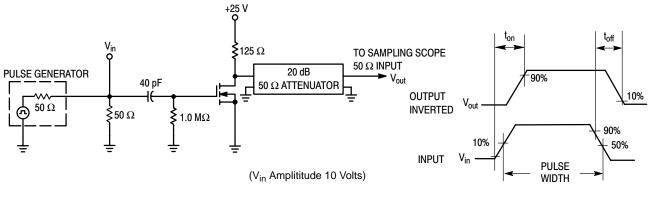


Figure 1. Switching Test Circuit

Figure 2. Switching Waveforms

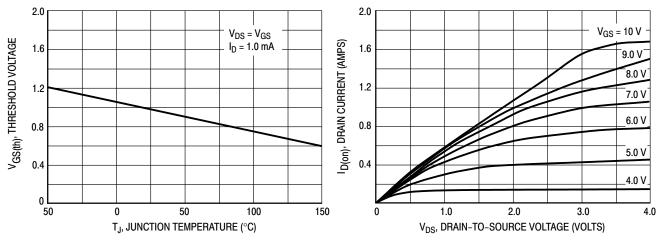
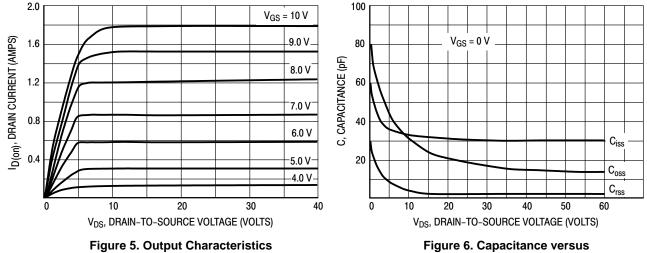




Figure 4. On–Region Characteristics

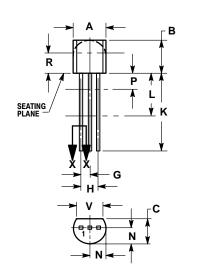


Drain–To–Source Voltage

VN0610LL

PACKAGE DIMENSIONS

TO-92 (TO-226AA) CASE 29-11 **ISSUE AL**





SECTION X-X

STYLE 22: SOURCE PIN 1. 2. GATE 3. DRAIN

NOTES

DIMENSIONING AND TOLERANCING PER ANSI Y14.5M. 1982.

CONTROLLING DIMENSION: INCH. CONTOULING DIMENSION: INCH. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED. 3.

LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM. 4

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
С	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
Ρ		0.100		2.54
R	0.115		2.93	
۷	0.135		3.43	

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